NSN 5962-01-317-2499

Memory Microcircuit - Page 1 of 1



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Body Length:

Between 1.380 inches and 1.420 inches

Body Width:

Between 0.560 inches and 0.600 inches

Body Height:

Between 0.040 inches and 0.180 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+155.0 degrees celsius

End Application:

5998-01-284-8573 electronic comp

Features Provided:

Hermetically sealed and high speed and positive outputs and burn in

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

14 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

First-in first-out

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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